

S o C b (S C)
MOSFET **m m E S C,**
960 m o , 1700 , M1,
TO-247-3L

N HL1000N170M1

Features

- Typ. $R_{DS(on)} = 960\text{ m}$

NVHL1000N170M1

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Max	Unit
- - -	θ		

NVHL1000N170M1

NVHL1000N170M1

NVHL1000N170M1

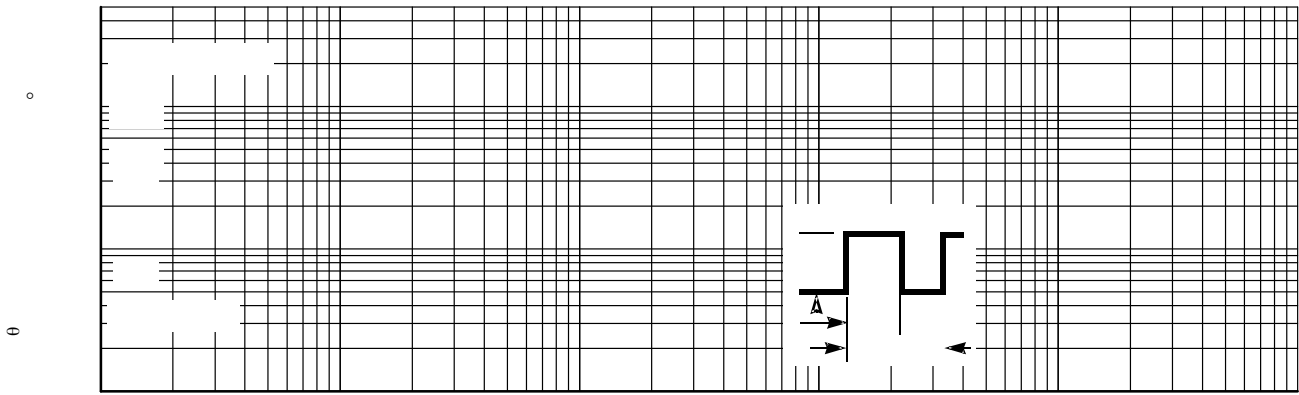


Figure 18. Transient Thermal Impedance

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